

# 60 V, 310 mA N-channel Trench MOSFET Rev. 1 — 17 June 2010

Product data sheet

#### 1. **Product profile**

### **1.1 General description**

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

#### 1.2 Features and benefits

- Logic-level compatible
- Very fast switching
- Trench MOSFET technology
- ESD protection up to 2 kV
- AEC-Q101 qualified

### 1.3 Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

### 1.4 Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	$T_{amb} = 25 \ ^{\circ}C$	-	-	60	V
V <sub>GS</sub>	gate-source voltage	T <sub>amb</sub> = 25 °C	-	-	±20	V
I <sub>D</sub>	drain current	$T_{amb} = 25 \ ^{\circ}C;$ $V_{GS} = 10 \ V$	<u>[1]</u> _	-	310	mA
R <sub>DSon</sub>	drain-source on-state resistance	T <sub>j</sub> = 25 °C; V <sub>GS</sub> = 10 V; I <sub>D</sub> = 500 mA	-	1	1.6	Ω

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.



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# 2. Pinning information

Table 2.	Pinning			
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		2
2	S	source		D
3	D	drain	1 2	G THE S
				017aaa000

# 3. Ordering information

Table 3. Ord	dering inform	nation	
Type number	Package		
	Namo	Description	Varsian

	Name	Description	Version
2N7002BKW	SC-70	plastic surface-mounted package; 3 leads	SOT323

### 4. Marking

Table 4. Marking codes	
Type number	Marking code <sup>[1]</sup>
2N7002BKW	X9*

- [1] \* = -: made in Hong Kong
  - \* = p: made in Hong Kong
  - \* = t: made in Malaysia \* = W: made in China

### 5. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>amb</sub> = 25 °C	-	60	V
$V_{GS}$	gate-source voltage	T <sub>amb</sub> = 25 °C	-	±20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V	<u>[1]</u>		
		T <sub>amb</sub> = 25 °C	-	310	mA
		T <sub>amb</sub> = 100 °C	-	215	mA
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$	-	1.2	А

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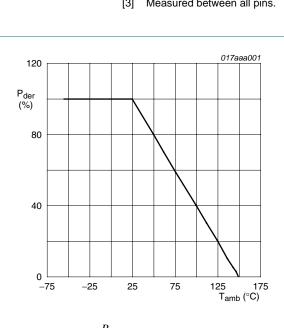
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In accordance with the Absolute Maximum Rating System (IEC 60134).					
Symbol	Parameter	Conditions	Min	Max	Unit
P <sub>tot</sub> tot	total power dissipation	T <sub>amb</sub> = 25 °C	[2] _	275	mW
			<u>[1]</u> -	330	mW
		T <sub>sp</sub> = 25 °C	-	880	mW
Tj	junction temperature			150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C
Source-d	Irain diode				
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	<u>[1]</u> -	310	mA
ESD maximum rating					
V <sub>ESD</sub>	electrostatic discharge voltage	human body model	<u>[3]</u> _	2000	V

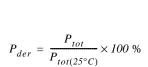
#### Table 5. Limiting values ... continued

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



Measured between all pins. [3]



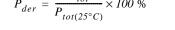


Fig 1. Normalized total power dissipation as a function of ambient temperature

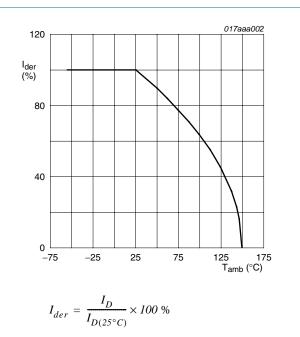
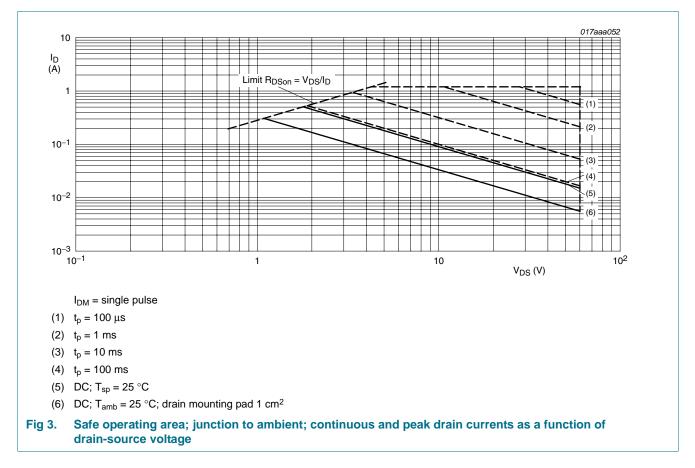


Fig 2. Normalized continuous drain current as a function of ambient temperature

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### 6. Thermal characteristics

#### Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from	in free air	<u>[1]</u> -	395	455	K/W
	junction to ambient		[2] _	330	380	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		-	-	140	K/W

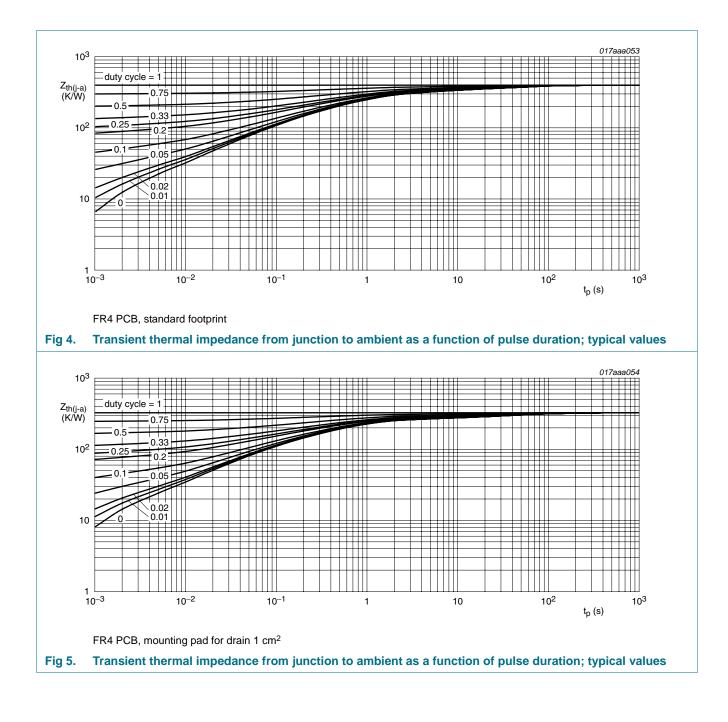
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.

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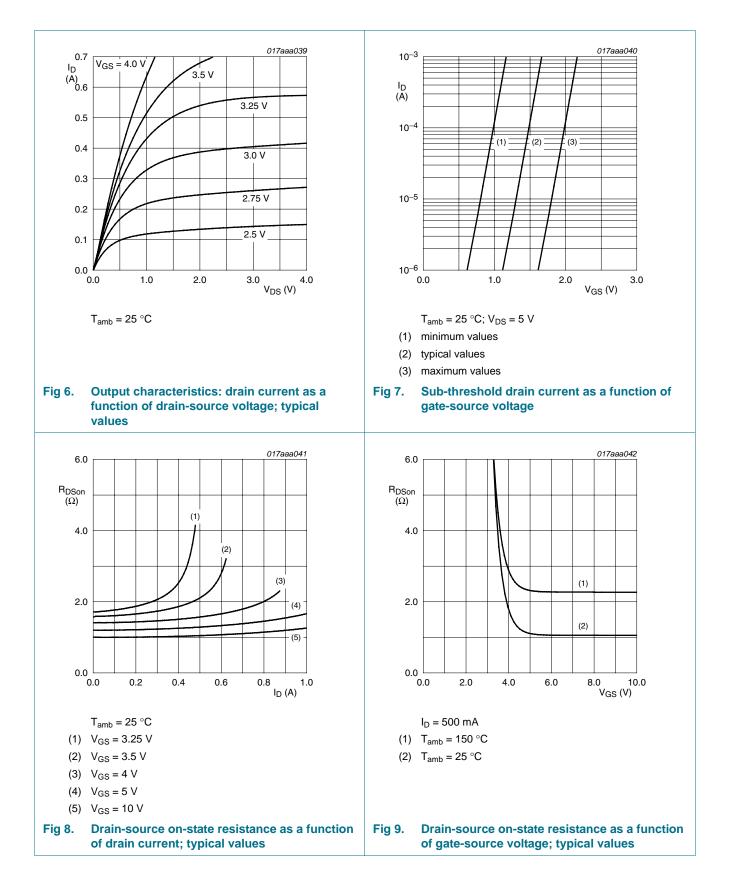
### 60 V, 310 mA N-channel Trench MOSFET

# 7. Characteristics

$T_j = 25 \ ^{\circ}C$	unless otherwise specified.					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D = 10 \ \mu A; \ V_{GS} = 0 \ V$	60	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	$I_D = 250 \ \mu\text{A}; \ V_{DS} = V_{GS}$	1.1	1.6	2.1	V
I <sub>DSS</sub>	drain leakage current	$V_{DS} = 60 \text{ V}; V_{GS} = 0 \text{ V}$				
		T <sub>j</sub> = 25 °C	-	-	1	μΑ
		T <sub>j</sub> = 150 °C	-	-	10	μΑ
I <sub>GSS</sub>	gate leakage current	$V_{GS}$ = ±20 V; $V_{DS}$ = 0 V	-	-	10	μΑ
R <sub>DSon</sub>	drain-source on-state		<u>[1]</u>			
	resistance	$V_{GS}$ = 5 V; $I_D$ = 50 mA	-	1.3	2	Ω
		$V_{GS}$ = 10 V; I <sub>D</sub> = 500 mA	-	1	1.6	Ω
<b>g</b> <sub>fs</sub>	forward transconductance	$V_{DS}$ = 10 V; I <sub>D</sub> = 200 mA	<u>[1]</u>	550	-	mS
Dynamic of	characteristics					
Q <sub>G(tot)</sub>	total gate charge	I <sub>D</sub> = 300 mA;	-	0.5	0.6	nC
Q <sub>GS</sub>	gate-source charge	<sup>–</sup> V <sub>DS</sub> = 30 V; – V <sub>GS</sub> = 4.5 V	-	0.2	-	nC
Q <sub>GD</sub>	gate-drain charge	$= V_{GS} = 4.5 V$	-	0.1	-	nC
C <sub>iss</sub>	input capacitance	$V_{GS} = 0 V; V_{DS} = 10 V;$	-	33	50	pF
C <sub>oss</sub>	output capacitance	f = 1 MHz	-	7	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	4	-	pF
t <sub>d(on)</sub>	turn-on delay time	V <sub>DD</sub> = 50 V;	-	5	10	ns
t <sub>r</sub>	rise time	R <sub>L</sub> = 250 Ω; - V <sub>GS</sub> = 10 V;	-	6	-	ns
t <sub>d(off)</sub>	turn-off delay time	$R_{G} = 6 \Omega$	-	12	24	ns
t <sub>f</sub>	fall time		-	7	-	ns
Source-dr	ain diode					
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 115 mA; V <sub>GS</sub> = 0 V	0.47	0.75	1.1	V

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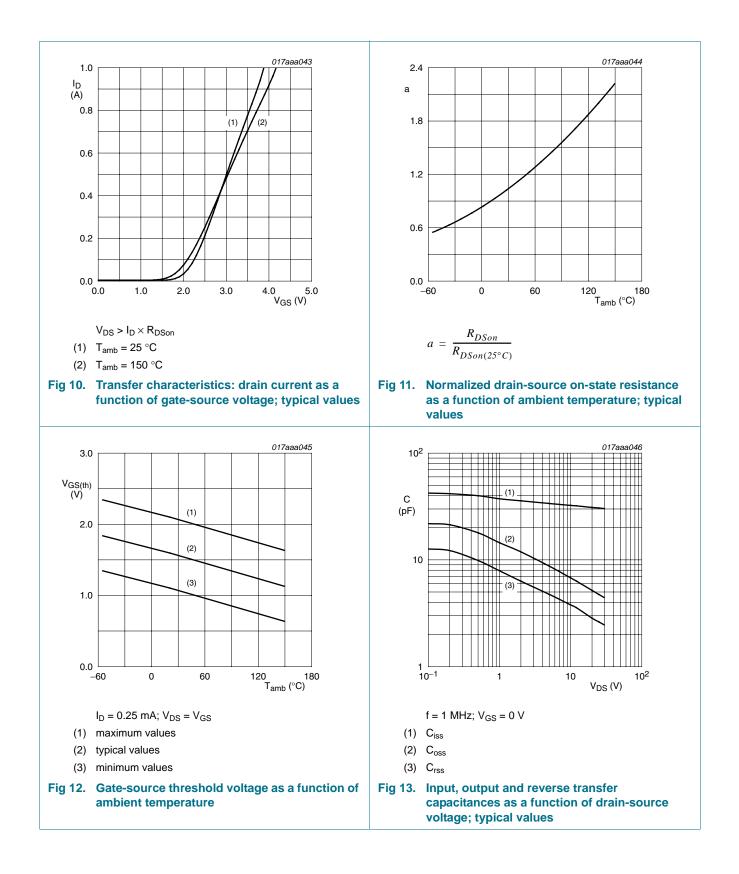


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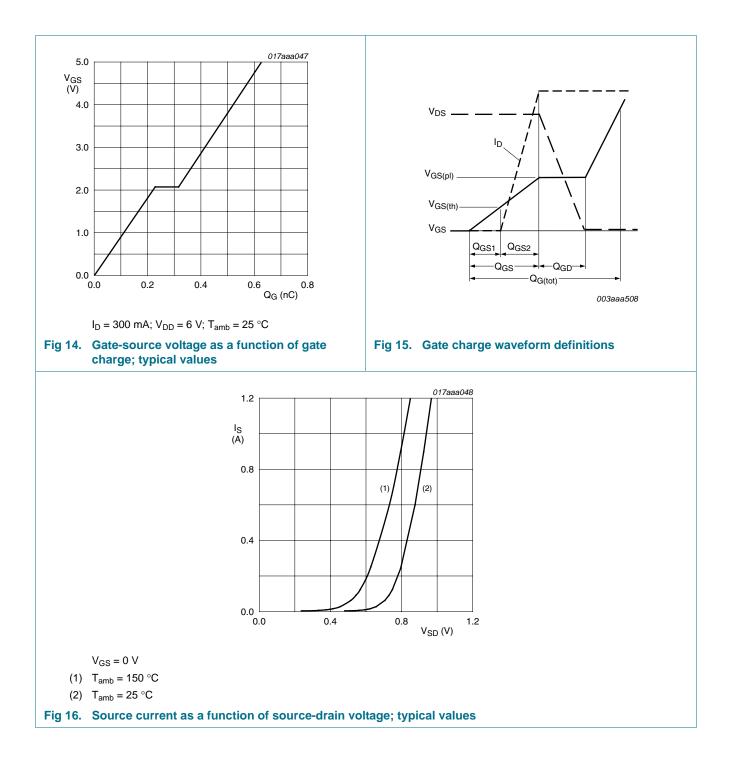


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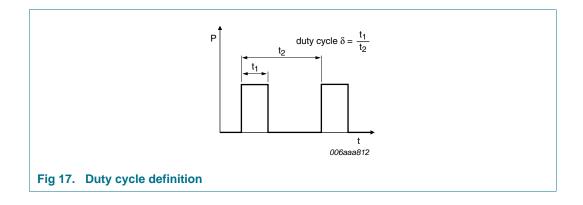
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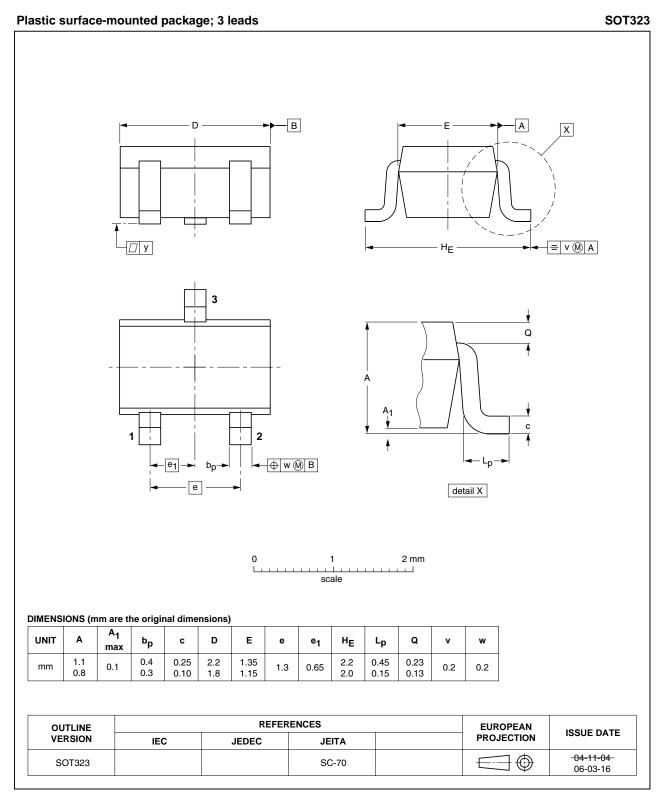
# 8. Test information



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### 9. Package outline



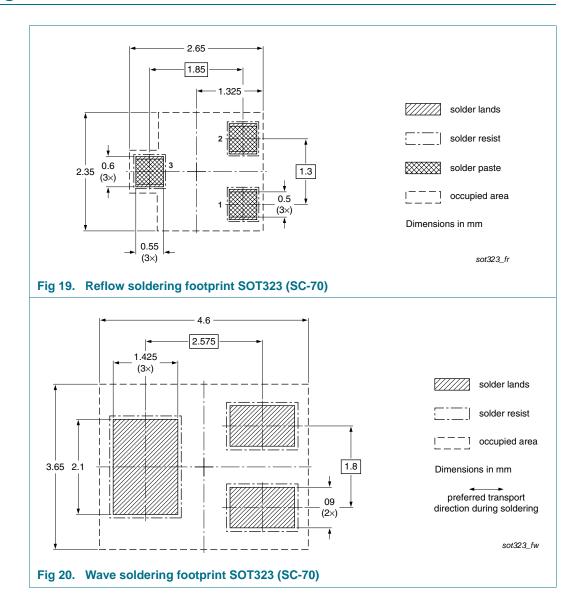
#### Fig 18. Package outline SOT323 (SC-70)

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### **10. Soldering**



### 60 V, 310 mA N-channel Trench MOSFET

# **11. Revision history**

Table 8. Ro	Revision history				
Document ID	I	Release date	Data sheet status	Change notice	Supersedes
2N7002BKW	v.1	20100617	Product data sheet	-	-

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#### 60 V, 310 mA N-channel Trench MOSFET

# **12. Legal information**

#### 12.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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